

T-91-60



Selection by Package

The product listed in Tables 1 through 22 have been compiled on an IBM or compatible personal computer disk for quick selection of product. This versatile disk may be obtained

by contacting a Motorola sales office in your area or by contacting a Motorola Literature Distribution Center listed on the back cover. Order the disk by requesting DK101/D.

Tables 1 through 22 are shown by package type. Within the tables the devices are arranged by breakdown voltage and on-resistance as the primary selection criteria. Device types shaded in Tables 1 through 8 are preferred devices recommended for new designs.

TMOS Power MOSFETS

Plastic Packages — TO-220AB

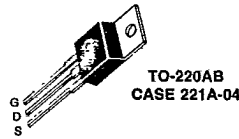


Table 1 — P-Channel

	V(BR)DSS (Volts) Min	rDS(on) @ ID		Device	ID (cont) Amps	PD* (Watts) Max	Page	
		(Ohms) Max	(Amps)					
	500	6	1	MTP2P50	2	75	3-407	
	450			MTP2P45			3-407	
	250	4	1.5	MTP3P25	3	75	3-427	
		3	2.5	MTP5P25	5		3-447	
		2	4	MTP8P25	8		3-462	
NEW	200	0.5	6	IRF9640	11	125	3-147	
		0.8	3.5	IRF9630	6.5		75	3-145
		1	2.5	MTP5P20	5		3-442	
	180			MTP5P18			3-442	
	100	0.4	4	MTP8P10	8	75	3-457	
		0.3	6	MTP12P10	12		3-493	
	80	0.4	4	MTP8P08	8	75	3-457	
				MTP12P08	12		3-493	
NEW	60	0.6	3.5	MTP7P06	7	75	3-651	
		0.3	6	MTP2955	12		3-806	
				MTP12P06			3-493	
	50	0.2	10	MTP20P06	20	100	3-740	
		0.6	3.5	MTP7P05	7	75	3-651	
		0.3	6	MTP12P05	12		3-493	

* @ 25°C

Bold Type indicates new product.

Shaded devices are preferred devices and are recommended for new designs.

MOTOROLA TMOS POWER MOSFET DATA

Table 2 — N-Channel

	V _{(BR)DSS} (Volts) Min	r _{DS(on)} @ I _D (Ohms) @ I _D (Amps)		Device	I _D (cont) Amps	P _D * (Watts) Max	Page
		Max					
NEW	1000	10	0.5	MTP1N100	1	75	3-392
		4	1.5	MTP3N100	3		3-606
	950	10	0.5	MTP1N95	1		3-392
		4	1.5	MTP3N95	3		3-606
	900	8	1	MTP2N90	2		3-402
		4	2	MTP4N90	4		3-606
	850	8	1	MTP2N85	2		3-402
		4	2	MTP4N85	4		3-606
	800	7	1.5	MTP3N80	3		3-417
		3	1.7	BUZ80A			3-79
NEW	750	7	1.5	MTP3N75		3-417	
		6	1	MTP2N60	2	3-566	
	600	2.5	1.5	MTP3N60	3	3-412	
		2	2.5	BUZ90	4	3-85	
		1.2	3	MTP6N60	6	125	3-641
550	12	0.5	MTP1N55	1	75	3-566	
	6	1	MTP2N55	2		3-586	
	2.5	1.5	MTP3N55	3		3-412	
	1.2	3	MTP6N55	6		125	3-641
500	8	0.5	MTP1N50	1	50	3-561	
		4	1	MTP2N50	2	75	3-397
	3	1.5	IRF820	2.5	40	3-139	
			MTP3N50	3	75	3-601	
			IRF832	4	3-141		
	2	1.5	IRF830	4.5	3-141		
			MTP4N50	4	3-432		
	1.1	4	IRF842	7	125	3-143	
			IRF840	8	3-143		
			MTP8N50		3-672		
450	8	0.5	MTP1N45	1	50	3-561	
		4	1	MTP2N45	2	75	3-397
	3	1	IRF823		40	3-139	
			IRF821	2.5	3-139		
	2	1.5	MTP3N45	3	75	3-601	
		2.5	IRF833	4	3-141		
	1.5	2	MTP4N45		3-432		
		2.5	IRF831	4.5	3-141		

* @ 25°C
Bold Type indicates new product.
 Shaded devices are preferred devices and are recommended for new designs.

MOTOROLA TMOS POWER MOSFET DATA



Table 2 — N-Channel — continued

V _{DS(on)} (Volts) Min	r _{DS(on)} (Ohms) Max	I _D (Amps)	Device	I _D (cont) Amps	P _D (Watts) Max	Page	
450	1.1	4	IRF843	7	125	3-143	
	0.85		IRF841	8		3-143	
	0.8		MTP8N45			3-672	
400	5	1	MTP2N40	2	50	3-581	
	3.3	1.5	MTP3N40	3	75	3-596	
	2.5		IRF722	2.5	40	3-133	
	1.8		IRF720	3		3-133	
	1.5	3	IRF732	4.5	75	3-135	
	1		IRF730			3-135	
			2.5	MTP5N40	5		3-437
		0.55		IRF740	10	125	3-137
			MTP10N40			3-704	
350	5	1	MTP2N35	2	50	3-581	
	1.5	3	IRF733	4.5	75	3-135	
	1		IRF731	5.5		3-135	
		2.5	MTP5N35	5		3-437	
		0.55	5	IRF741	10	125	3-137
	MTP10N35			3-704			
250	2	1	MTP2N25	2	50	3-576	
	0.45	5	MTP10N25	10	100	3-478	
200	2.4	1.25	IRF612	2	20	3-123	
	1.8	1	MTP2N20		50	3-571	
	1.5	1.25	IRF610	2.5	20	3-123	
	1		MTP5N20	5	75	3-631	
	0.8		IRF620		40	3-125	
	0.7	3.5	MTP7N20	7	75	3-646	
	0.6	5		IRF632	8		3-127
				IRF630	9		3-127
	0.4	4		MTP8N20	8		3-452
				BUZ73	7	40	3-75
	0.35	6	MTP12N20	12	100	3-714	
	0.22	10		IRF642	16	125	3-129
				IRF640	18		3-129
150	0.8	2.5	IRF621	4	40	3-125	
	0.4	5	IRF631	9	75	3-127	
			MTP10N15	10		3-699	
	0.25	7.5	MTP15N15	15	100	3-729	
	0.22	10	IRF643	16	125	3-129	

* @ 25°C

Shaded devices are preferred devices and are recommended for new designs.

MOTOROLA TMOS POWER MOSFET DATA

Table 2 — N-Channel — continued

V(BR)DSS (Volts) Min	r _{DS(on)} (Ohms) Max	I _D (Amps)	Device	I _D (cont) Amps	P _D [*] (Watts) Max	Page
150	0.18	10	IRF641	18	125	3-129
120	0.3	5	MTP10N12L	10	75	3-473
	0.9	2.5	MTP5N12	5	50	3-626
	1.2	1.5	MTP3N12	3		**
100	0.8	3	MTP6N10	6	20	3-636
		2	IRF512	3.5		3-115
	0.6		IRF510	4	3-115	
	0.5	4	MTP8N10	8	75	3-656
			MTP8N10E			3-661
	0.4		IRF522	7	40	3-117
	0.33	5	MTP10N10	10	75	3-682
	0.3	4	IRF520	8	40	3-117
	0.25	5	MTP10N10E	10	75	3-687
		8	IRF532	12		3-119
	0.18		IRF530	14		3-119
		6	MTP12N10	12	100	3-488
	0.15	10	MTP20N10	20		3-519
			MTP20N10E			3-734
	0.11	15	IRF542	24	125	3-121
	0.085		IRF540	27		3-121
		12.5	MTP25N10	25		3-757
	0.075		MTP25N10E			3-762
80	0.8	2	MTP4N08	4	50	3-616
	0.5	4	MTP8N08	8	75	3-656
	0.33	5	MTP10N08	10		3-682
	0.18	6	MTP12N08	12	3-488	
	0.15	10	MTP20N08	20	100	3-519
60	0.8	2	IRF513	3.5	20	3-115
	0.6		IRF511	4		3-115
		2.5	MTP5N06	5	50	3-621
	0.4	3.5	MTP7N06	7		**
		4	IRF523		40	3-117
	0.3		IRF521	8		3-117
	0.28	5	MTP10N06	10	75	3-677
	0.25	8	IRF533	12		3-119
	0.2	5	MTP10N06E	10		3-467
		6	MTP12N06			3-483
	0.18	8	IRF531	14		3-119

* @ 25°C

**Contact Motorola sales office for data sheet.

Shaded devices are preferred devices and are recommended for new designs.

MOTOROLA TMOS POWER MOSFET DATA

Table 2 — N-Channel — continued

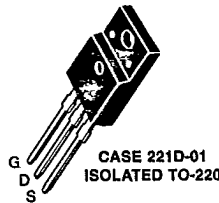
V(BR)DSS (Volts) Min	rDS(on) (Ohms) Max	ID (Amps)	Device	ID (cont) Amps	PD* (Watts) Max	Page			
60	0.16	7.5	MTP15N06	15	75	3-719			
			MTP15N06E			3-503			
	0.085	15	6	MTP3055E	12	40	3-811		
			IRF541	27			125	3-121	
	0.08	12.5	12.5	MTP25N06	25	100	3-524		
				MTP25N06E			3-751		
0.055	17.5	17.5	MTP35N06E	35	125	3-781			
50	0.6	2.5	MTP5N05	5	50	3-621			
			MTP10N05			10	75	3-677	
	0.28	5	5	MTP15N05	15	75	3-719		
				MTP15N05			15	75	3-719
	0.12	6	6	BUZ71A	12	40	3-70		
				MTP12N05E			12	40	**
				IRFZ22			14	40	3-165
	0.1	6	6	BUZ71	12	40	3-70		
				MTP15N05E			15	75	**
	0.08	12.5	12.5	IRFZ20	25	100	3-165		
				MTP25N05			25	100	3-524
	0.07	12.5	12.5	MTP25N05E	25	100	3-745		
				IRFZ32			25	100	3-167
	0.06	15	15	BUZ11A	15	75	3-67		
				MTP30N08E			30	75	3-768
	0.05	15	15	BUZ11	15	75	3-67		
				MTP30N08E			30	75	3-768
	0.04	15	15	BUZ11	15	75	3-67		
				MTP30N08E			30	75	3-768
	0.035	29	29	MTP45N06E	45	125	3-539		
IRFZ42				46			125	3-169	
0.028	25	25	MTP50N05E	50	125	3-550			
			IRFZ40			51	125	3-169	

* @ 25°C
 **Contact Motorola sales office for data sheet.
 Shaded devices are preferred devices and are recommended for new designs.

Table 3 — N- and P-Channel — Isolated TO-220

	V(BR)DSS (Volts) Min	rDS(on) (Ohms) Max	ID (Amps)	Device	ID (cont) Amps	PD* (Watts) Max	Page	
NEW	60	0.3	6	MTA2955***	7	33	**	
NEW				MTP3055E			10	**
NEW		0.1	7.5	7.5	MTA15N06E	15	40	**
NEW		0.028	25	25	MTA30N06E	30	50	**

* @ 25°C
 **Contact Motorola sales office for data sheet.
 ***Indicates P-Channel
 Shaded devices are preferred devices and are recommended for new designs.



MOTOROLA TMOS POWER MOSFET DATA



TMOS Power MOSFETs
Plastic Packages — TO-218AC

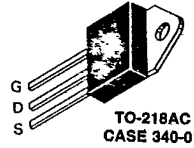


Table 4 — P-Channel

$V_{(BR)DSS}$ (Volts) Min	$r_{DS(on)}$ (Ohms) Max	I_D (Amps)	Device	I_D (cont) Amps	P_D^* (Watts) Max	Page
200	0.7	4	MTH8P20	8	125	3-314
180			MTH8P18			3-314
100	0.15	10	MTH20P10	20		3-339
80			MTH20P08			3-339
60	0.14	12.5	MTH25P06	25		3-349
50			MTH25P05			3-349

* @ 25°C
Shaded devices are preferred devices and are recommended for new designs.

Table 5 — N-Channel

	$V_{(BR)DSS}$ (Volts) Min	$r_{DS(on)}$ (Ohms) Max	I_D (Amps)	Device	I_D (cont) Amps	P_D^* (Watts) Max	Page
NEW	1000	2	3	MTH6N100	6	150	3-287
		3	2.5	MTH5N100	5		3-272
	950			MTH5N95			3-272
NEW	900	1.8	4	MTH8N90	8	170	3-308
		3	3	MTH6N90	6	150	3-282
	850			MTH6N85			3-282
NEW	800	1.5	3.8	BUZ355		125	3-91
	600	1.2	3	MTH6N60		150	3-277
		0.5	4	MTH8N60	8		3-303
	550	1.2	3	MTH6N55	6		3-277
		0.5	4	MTH8N55	8		3-303
NEW	500	0.8	3.5	MTH7N50	7		3-293
		0.6	6	BUZ330	9.5	125	3-87
		0.4	7	MTH13N50	13	150	3-319
	450	0.8	3.5	MTH7N45	7		3-293
		0.4	7	MTH13N45	13		3-319
	400	0.55	4	MTH8N40	8		3-298
		0.3	7.5	MTH15N40	15		3-329
	350	0.55	4	MTH8N35	8		3-298
		0.3	7.5	MTH15N35	15		3-329
NEW	250	0.14	15	MTH30N25	20	125	3-359

* @ 25°C
Bold Type Indicates new product.
Shaded devices are preferred devices and are recommended for new designs.



Table 5 — N-Channel — continued

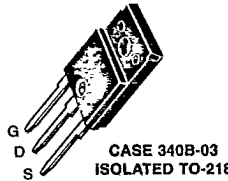
V _{(BR)DSS} (Volts) Min	r _{DS(on)} @ I _D (Ohms) (Amps)		Device	I _D (cont) Amps	P _D * (Watts) Max	Page
	Max					
200	0.16	7.5	MTH15N20	15	150	3-324
	0.08	15	MTH30N20	30		3-354
150	0.12	10	MTH20N15	20	125	3-334
	0.06	17.5	MTH35N15	35		3-376
100	0.07	12.5	MTH25N10	25	125	3-344
	0.04	20	MTH40N10	40		3-381
80	0.07	12.5	MTH25N08	25	125	3-344
	0.04	20	MTH40N08	40		3-381
60	0.055	17.5	MTH35N06	35	125	3-365
			MTH35N06E			3-370
	0.028	20	MTH40N06	40		3-381
50	0.055	17.5	MTH35N05	35	125	3-365
			MTH40N05			40
	0.028	20	MTH50N05E	50		3-386

NEW

* @ 25°C
Bold Type indicates new product.
Shaded devices are preferred devices and are recommended for new designs.

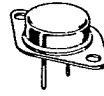
Table 6 — N- and P-Channel Isolated TO-218

V _{(BR)DSS} (Volts) Min	r _{DS(on)} @ I _D (Ohms) (Amps)		Device	I _D (cont) Amps	P _D * (Watts) Max	Page
	Max					
500	0.4	7	MTG9N50E	9	70	**
200	0.08	15	MTG20N20	20	70	**
100	0.15	10	MTG15P10***	15	70	**

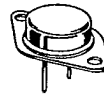


NEW
NEW
NEW

* T_C = 25°C
** Contact Motorola sales office for data sheet.
*** Indicates P-Channel
Bold Type indicates new product.



TO-204AA
CASE 1-06



TO-204AE
CASE 197A-02

TMOS Power MOSFETs

Metal Packages — TO-204AA/AE

Table 7 — P-Channel

V _{(BR)DSS} (Volts) Min	r _{DS(on)} @ I _D		Device	I _D (cont) Amps	P _D * (Watts) Max	Page	
	(Ohms) Max	(Amps)					
500	6	1	MTM2P50	2	75	3-407	
450			MTM2P45			3-407	
250	4	1.5	MTM3P25	3		3-427	
	3	2.5	MTM5P25	5		3-447	
	2	4	MTM8P25	8		3-462	
200	1	2.5	MTM5P20	5		3-442	
	0.7	4	MTM8P20	8		125	3-314
180	1	2.5	MTM5P18	5		75	3-442
	0.7	4	MTM8P18	8		125	3-314
100	0.4		MTM8P10			75	3-457
	0.3	6	MTM12P10	12		3-493	
	0.15	10	MTM20P10	20	125	3-339	
80	0.4	4	MTM8P08	8	75	3-457	
	0.3	6	MTM12P08	12		3-493	
	0.15	10	MTM20P08	20	125	3-339	
60	0.3	6	MTM12P06	12	75	3-493	
	0.14	12.5	MTM25P06	25	125	3-349	
50	0.3	6	MTM12P05	12	75	3-493	
	0.2	10	MTM20P05	20	100	**	
	0.14	12.5	MTM25P05	25	125	3-349	

* @ 25°C
**Contact Motorola sales office for data sheet.
Shaded devices are preferred devices and are recommended for new designs.

Table 8 — N-Channel

V _{(BR)DSS} (Volts) Min	r _{DS(on)} @ I _D		Device	I _D (cont) Amps	P _D * (Watts) Max	Page
	(Ohms) Max	(Amps)				
1000	10	0.5	MTM1N100	1	75	3-392
	4	1.5	MTM3N100	3	125	3-422
	3	2.5	MTM5N100	5	150	3-272
	1.2	5	MTM10N100E	10	300	**

NEW

* @ 25°C
**Contact Motorola sales office for data sheet.
Shaded devices are preferred devices and are recommended for new designs.

Table 8 — N-Channel — continued

V _{BRDSS} (Volts) Min.	r _{DS(on)} @ I _D (Ohms) Max.	I _D (Amps)	Device	I _D (cont) (Amps)	P _D [*] (Watts) Max.	Page
950	10	0.5	MTM1N95	1	75	3-392
	4	1.5	MTM3N95	3	125	3-422
	3	2.5	MTM5N95	5	150	3-272
900	8	1	MTM2N90	2	75	3-402
	4	2	MTM4N90	4	125	3-422
	3	3	MTM6N90	6	150	3-282
850	8	1	MTM2N85	2	75	3-402
	4	2	MTM4N85	4	125	3-422
	3	3	MTM6N85	6	150	3-282
800	7	1.5	MTM3N80	3	75	3-417
	2	3	BUZ84	5.3	125	3-83
	1.5		BUZ84A	6		3-83
750	7	1.5	MTM3N75	3	75	3-417
600	2.8	3	2N6823			3-48
	2.5	1.5	MTM3N60			3-412
	1.8	6	2N6826	6	150	3-53
	1.2	3	MTM6N60			3-277
	0.5	4	MTM8N60	8		3-303
500	4	1	MTM2N50	2	75	3-397
	1.5	2	MTM4N50	4		3-432
		3	2N6762	4.5		3-18
	0.85	4	IRF440	8	125	3-111
	0.8	3.5	MTM7N50	7	150	3-293
NEW	0.5	7	IRF452	12		3-113
	0.4		IRF450	13		3-113
		7.75	2N6770	12		3-37
	7.5	MTM15N50	15	250	3-514	
	0.25	12	MTM24N50E	24	300	**
450	1.5	2	MTM4N45	4	75	3-432
	0.85	4	IRF441	8	125	3-111
	0.8	3.5	MTM7N45	7	150	3-293
	0.4	7	IRF451	13		3-113
		7.5	MTM15N45	15	250	3-514

* @ 25°C

**Contact Motorola sales office for data sheet.

Shaded devices are preferred devices and are recommended for new designs.

MOTOROLA TMOS POWER MOSFET DATA

Table 8 — N-Channel — continued

V _{GS} (Volts) Min	r _{DS(on)} @ I _D (Ohms)		Device	I _D (cont) (Amps)	P _D * (Watts) Max	Page
	Max	(Amps)				
400	1	3	IRF330	5.5	75	3-105
		2.5	MTM5N40	5		3-437
		3.5	2N6760	5.5		3-14
	0.55	5	IRF340	10	125	3-107
		4	MTM8N40	8	150	3-298
	0.3	8	IRF350	15	250	3-109
		9	2N6768	14		3-32
		7.5	MTM15N40	15		3-509
		13	MTM26N40E	26		**
	350	1.5	3	IRF333	4.5	75
2N6769				3-14		
1		2.5	IRF331	5	150	3-105
			MTM5N35			5
0.3		8	IRF351	15	250	3-109
		7.5	MTM15N35			3-509
250	0.45	5	MTM10N25	10	100	3-478
200	0.4	4	IRF230	9	75	3-99
			2N6768			3-10
			MTM8N20			8
	0.18	10	IRF240	18	125	3-101
	0.18	7.5	MTM15N20	15	150	3-324
	0.12	16	IRF252	25		3-103
	0.085	19	IRF250	30		3-103
			2N6766	3-27		
0.08	20	MTM40N20	40	250	3-534	
150	0.22	10	IRF243	16	125	3-101
			IRF241			18
	0.12	10	MTM20N15	20	150	3-334
			IRF253	25		3-103
	0.085	16	IRF251	30	3-103	
	0.06	22.5	MTM45N15	45	250	3-545
100	0.18	8	IRF130	14	75	3-93
		6	MTM12N10	12		3-488
		9	2N6756	14		3-6
	0.15	10	MTM20N10	20	100	3-519
	0.11	15	IRF142	24	125	3-95
			IRF140	27		3-95
	0.08	20	IRF152	33	150	3-97

* @ 25°C
 **Contact Motorola sales office for data sheet.
 Shaded devices are preferred devices and are recommended for new designs.

MOTOROLA TMOS POWER MOSFET DATA



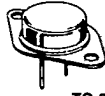
Table 8 — N-Channel — continued

V _{DS} (Volts) Min	r _{DS(on)} (Ohms) Max	I _D (Amps)	Device	I _D (cont) Amps	P _D (Watts) Max	Page
100	0.075	12.5	MTM25N10E	25	150	**
	0.07		MTM25N10			3-344
	0.055	20	IRF150	40		3-97
		24	2N6764	38		3-22
	0.04	27.5	MTM55N10	55	250	3-556
80		MTM55N08			3-556	
60	0.15	7.7	MTM15N06E	17	75	3-503
	0.085	15	IRF141	27	125	3-95
	0.055	17.5	MTM35N06	35	150	3-365
			MTM35N06E			3-370
		20	IRF151	40		3-97
0.028	30	MTM60N06	60	250	3-556	
50	0.2	6	MTM12N05	12	75	3-483
	0.055	17.5	MTM35N05	35	125	3-365
	0.035	29	MTM45N05E	45		3-539
	0.028	25	MTM50N05E	50		3-550
30		MTM60N05	60	250	3-556	

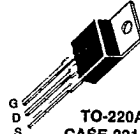
* @ 25°C

**Contact Motorola sales office for data sheet.

Shaded devices are preferred devices and are recommended for new designs.



TO-204AA
(TO-3)
CASE 1-06



TO-220AB
CASE 221A-04



TO-251
CASE 369-03



TO-252
CASE 369A-04

TMOS Power MOSFETs

Logic Level Power MOSFETs

Logic level MOSFETs are fully enhanced with 5 volts applied to the gate.

Table 9 — N-Channel Logic Level Power MOSFETs (TO-204AA and TO-220AB)

	V _{(BR)DSS} (Volts) Min	r _{DS(on)} (Ohms) Max	@ I _D (Amps)	Device	I _{D(cont)} (Amps)	P _D @ T _C = 25°C Watts	Package TO-	Page				
NEW	150	0.3	5	MTM10N15L	10	75	204AA	3-473				
				MTP10N15L			220AB	3-473				
				MTP8N15L				3-667				
	120	0.3	5	MTM10N12L	10		204AA	3-473				
				MTP10N12L			220AB	3-473				
	100	0.2	6	MTM12N10L	12		204AA	**				
				MTP12N10L			220AB	3-709				
				MTP3N10L				3-591				
NEW	80	0.135	7.5	MTP15N08L	15			3-724				
				MTM12N08L			12	204AA	**			
				MTP12N08L				220AB	3-709			
NEW	60	0.06	20	MTP40N06EL	40	150		3-591				
				MTM25N06L			25	204AA	3-529			
				MTP25N06L				220AB	3-529			
		0.15	7.5	MTM15N06L	15	75	204AA	3-498				
				MTP15N06L			220AB	3-498				
				NEW			0.18	6	MTP3055EL	12	40	
MTD3055EL	TO-252	3-266										
MTD3055EL1		TO-251	3-266									
NEW	50	0.032	25	MTP4N06L	4	25	220AB	3-611				
				0.08			12.5	MTP50N05EL	50	150		3-900
								MTM25N05L			25	204AA
	0.15	7.5	15	MTP25N05L	15	75	220AB	3-529				
				MTM15N05L			204AA	3-498				
				MTP15N05L			220AB	3-498				
	0.6	2		MTP4N05L	4	25		3-611				

**Contact Motorola sales office for data sheet.
Bold Type Indicates new product.
 Shaded devices are preferred devices and are recommended for new designs.



TMOS Power MOSFETs

Hermetic, Isolated, Tab Mount Power MOSFETs

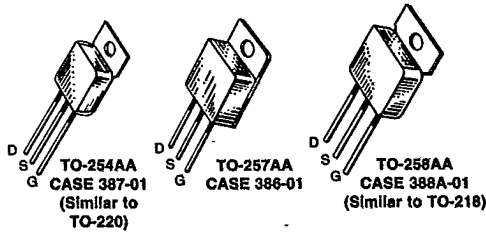


Table 10 — TO-254AA, TO-257AA, and TO-258AA
ALL NEW DEVICES**

	V _{(BR)DSS} (Volts) Min	r _{DS(on)} (Ohms) Max	@	I _D (Amps)	Device	I _{D(Cont)} Amps	P _D @ T _C = 25°C Watts	Package TO-
NEW	1000	3		2.5	MHR5N100	5	125	258AA
NEW					MHM5N100			254AA
NEW		8	0.5	MHT1N100	1	50	257AA	
NEW	800	6		1	MHT2N80	2		
NEW	500	0.4		7	MHR15N50	15	125	258AA
NEW					MHM12N50			12
NEW		1.8	3.5	MHR7P50*	7		258AA	
NEW		MHM7P50*				254AA		
NEW		1.5	3	MHT4N50	4	50	257AA	
NEW		6	1	MHT2P50*	2			
NEW	200	0.1		16	MHR30N20	30	125	258AA
NEW					MHM25N20	25		254AA
NEW		0.4	6	MHT8N20	8	50	257AA	
NEW		0.75		4	MHR8P20*		125	258AA
NEW					MHM8P20*			
NEW	MHT8P20*				257AA			
NEW	100	0.065		20	MHR35N10	35		258AA
NEW					MHM25N10	25		254AA
NEW		0.15	10	MHM20P10*	20			
NEW		0.2	5	MHT10N10	10	50	257AA	
NEW	0.3		MHT12P10*					
NEW	60	0.05		15	MHR35N06M	35	125	CASE 388-01

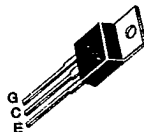
*Indicates P-Channel
 **Contact Motorola sales office for data sheet.
 Bold Type Indicates new product.
 Note: All of these devices can be purchased with JTX or JTXV equivalent processing by adding HX or HVX suffix to device type.



TMOS Insulated Gate Bipolar Transistors

Gain Enhanced MOSFETs (IGBTs)

This relatively new series of power transistors combines the high input resistance of a MOSFET with the low internal on-resistance of a bipolar transistor to provide more efficient performance than either a MOSFET or bipolar device in low-frequency switching service. Recommended for motor drive circuits, home appliances, and other applications where high switching speed is not a requirement. All are N-Channel.

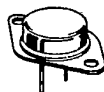


TO-220AB
CASE 221A-04

Table 11 — TO-220AB

V _{BR} (V _{CE}) (Volts) Min	r _{CE(on)} @ I _C (Ohms) @ I _C (Amps)		Device	I _C (cont) Amps	P _D [*] (Watts) Max	Page
	Max					
500	0.27	10	MGP20N50	20	100	3-184
	1.6	2.5	MGP5N50	5	50	3-180
450	0.27	10	MGP20N45	20	100	3-184
	1.6	2.5	MGP5N45	5	50	3-180

* @ 25°C



TO-204AA
(TO-3)
CASE 1-06

Table 12 — TO-204AA

V _{BR} (V _{DS}) (Volts) Min	r _{DS(on)} @ I _D (Ohms) @ I _D (Amps)		Device	I _D (cont) Amps	P _D [*] (Watts) Max	Page
	Max					
500	0.27	10	MGM20N50	20	100	3-184
	1.6	2.5	MGM5N50	5	50	3-180
450	0.27	10	MGM20N45	20	100	3-184
	1.6	2.5	MGM5N45	5	50	3-180

* @ 25°C



TMOS SENSEFETs

SENSEFETs are conventional power MOSFETs with an option provided to sense the drain current by measuring a small proportion of the total drain current. These devices are ideal for current mode switching regulators and motor controls.

CASE 314B
(5 PIN TO-220)

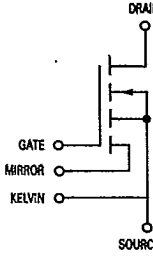


Table 13 — Case 314B

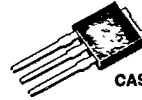
	V(BR)DSS (Volts) Min	rDS(on) (Ohms) Max	ID @ ID (Amps)	Device	ID (cont) Amps	PD* (Watts) Max	Page
NEW	80	0.04	20	MTP40N06M	40	125	3-783
NEW	80	0.065	15	MTP30N08M	30		3-774
	100	0.25	5	MTP10N10M	10	75	3-693
		0.085	12.5	MTP25N10M	25	100	**
	250	1.5	4	MTP4N25M	4	75	**
		0.45	2	MTP10N25M	10	100	**

* @ 25°C
**Contact Motorola sales office for data sheet.
Bold Type Indicates new product.

DPAK



CASE 369A-04****
TO-252



CASE 369-03***
TO-251

Table 14 — Case 369A-04 Surface Mount
Case 369-03 Insertion Mountable

	V(BR)DSS (Volts) Min	rDS(on) (Ohms) Max	ID @ ID (Amps)	Device	ID (cont) Amps	PD* (Watts) Max	Page
	500	4	1	MTD2N50	2	1.75**	3-218
	400	5	0.5	MTD1N40	1		3-208
	200	0.7	2	MTD4N20	4		3-224
NEW				1.5	1	MTD2N20	2
	150	0.3	3	MTD6N15	6		3-244
	100	0.25		MTD6N10			3-239
	80			MTD6N08			3-239
	60	0.6	2	MTD4P06†	4		3-229
		0.4	2.5	MTD5N06	5		3-234
		0.3	6	MTD2955†	12		3-255
NEW	50	0.15	4	MTD3055E	8		3-260
		0.6	2	MTD4P05†	4		3-229
		0.4	2.5	MTD5N05	5		3-234
		0.1	5	MTD10N05E	10		3-249

* @ 25°C
**Power rating when mounted on a board with the minimum pad size recommended.
***Add -1 Suffix to part number to order Insertion mountable package.
****Available in tape and reel.
† Indicates P-Channel
Bold Type Indicates new product.
Shaded devices are preferred devices and are recommended for new designs.



TMOS Power MOSFETs
Multiple Chip Products



CASE 806-02

Table 15 — Multiple Chip Products in the Isolated ICePAK*

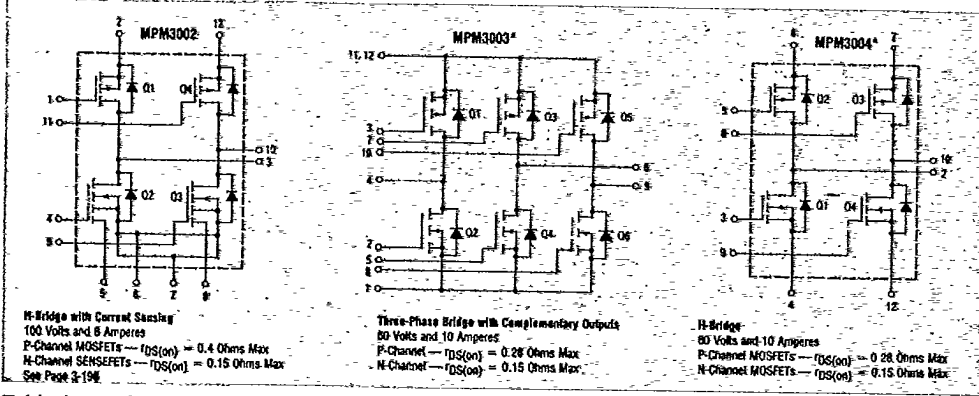


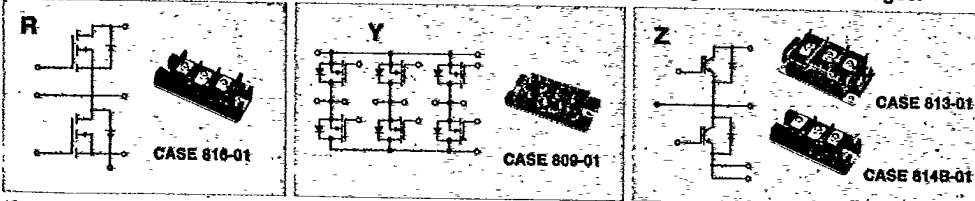
Table 16 — TMOS Power MOSFET Modules*

Max I_D (cont) Amps	Max V_{DSS} Volts	Device Type	Module Type	Max $V_{DS(on)}$ Volts	Conditions			Max. Resistive Switching			P_D Watts $T_C = 25^\circ C$	Case No.	Circuit Config.	
					I_D Amps	V_{GS} Volts	t_{on} μs	t_{off} μs	t_f μs	Conditions				
15	450	MT16FR45	Six-pack	6	15x6	10	0.6	2	0.5	15	10	125x6	809-01	Y
50	450	MT50BY45	Dual	7	50	10	0.8	1.3	0.2	50	10	400x2	816-01	R

Table 17 — IGBT Power Modules*

Max I_C (cont) Amps	Max V_{CES} Volts	Device Type	Module Type	Max V_{CE} Volts	Conditions			Max. Resistive Switching			P_D Watts $T_C = 25^\circ C$	Case No.	Circuit Config.	
					I_C Amps	V_{GE} Volts	t_{on} μs	t_s μs	t_f μs	Conditions				
25	1000	MG25BZ100	Dual	5	25	15	1	2	1	25	15	200x2	813-01	Z
50	1000	MG50BZ100	Dual	5	50	15	1	1.5	1	50	15	300x2	813-01	Z
100	1000	MG100BZ100	Dual	5	100	15	1	1.5	1	100	15	400x2	814B-01	Z
25	500	MG25BZ50	Dual	5	25	15	1	1.5	1	25	15	125x2	813-01	Z
50	500	MG50BZ50	Dual	5	50	15	1	1.5	1	50	15	300x2	813-01	Z
75	500	MG75BZ50	Dual	5	75	15	1	1.5	1	75	15	350x2	813-01	Z
100	500	MG100BZ50	Dual	5	100	15	1	1.5	1	100	15	400x2	813-01	Z

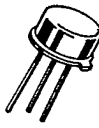
Table 18 — TMOS Power MOSFET and IGBT Power Module Circuit Configurations and Packages.*



*Contact Motorola sales office for data sheets.



Small-Signal MOSFETs



TO-205AF
(TO-39)
CASE 79-05

Table 19 — Switches and Choppers — TO-205AF

V _{DS(s)} (Volts)	r _{DS(on)} @ I _D (Ohms)	I _D (Amps)	Device	I _{D(Cont)} (Amps)	P _D @ T _C = 25°C (Watts)	Page
240	6	0.5	VN2406B	0.63	2.5	**
	10	0.5	VN2410B	0.63	2.5	**
200	0.8	2.25	2N6790-	3.5	20	**
	0.8	2	IRFF220	3.5	20	3-163
	1.5	1.5	2N6784	2.25	15	3-44
	6.4	0.25	MFE9200	0.4	1.8	3-177
170	6	0.5	VN1706B	0.63	2.5	**
	10	0.5	VN1710B	0.63	2.5	**
100	0.3	3	IRFF120	6	20	3-161
90	4	1	2N6661	0.9	6.25	3-2
60	3	1	2N6660	1.1	6.25	3-2
	5	0.5	MFE910	1	6.25	3-171
35	1.8	1	2N6659	1.4	6.25	**
30	1.2	1	VN0300B	1.25	6.25	**

**Contact Motorola sales office for data sheet.

Table 20 — 4-Pin Dip — Case 370-01



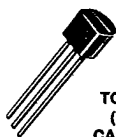
CASE 370-01

P_D @ T_C = 25°C 1 Watt Max

V _{BR(DSS)} (Volts) Min	r _{DS(on)} @ I _D (Ohms) Max	I _D (Amp)	Device	I _{D(Cont)} (Amp) Max	Page
200	0.8	0.4	IRFD220	0.8	3-157
	1.5	0.3	IRFD210	0.6	3-155
150	2.4	0.3	IRFD213	0.45	3-155
100	0.3	0.6	IRFD120	1.3	3-153
	0.6	0.8	IRFD110	1	3-151
	0.6	-0.8	IRFD9120	-1	**
	1.2	-0.3	IRFD9110	-0.7	**
	2.4	0.25	IRFD120	0.5	3-149
60	0.4	0.6	IRFD123	1.1	3-153
	0.8	0.8	IRFD113	0.8	3-151
	0.8	-0.8	IRFD9123	-0.8	**

**Contact Motorola sales office for data sheet.

MOTOROLA TMOS POWER MOSFET DATA



TO-226AA
(TO-92)
CASE 29-04

Table 21 — Plastic — TO-226AA

V(BR)DSS	r _{DS(on)} @ I _D		Device	I _D (Cont) (Amp) Max	P _D @ T _C = 25°C Watts Max	Page
	Max	(Ohms) (Amp)				
240	6	0.5	VN2406L	0.158	0.4	**
	10	0.5	VN2410L	0.12	0.4	**
200	6.4	0.25	BS107A	0.25	0.6	**
	6.4	0.25	MPF9200	0.4	0.5	3-195
	14	0.2	BS107	0.25	0.6	**
170	6	0.5	VN1706L	0.158	0.4	**
	10	0.5	VN1710L	0.12	0.4	**
150	12	0.1	MPF4150†	0.25	0.625	3-193
60	5	0.5	2N7000	0.5	0.4	3-58
	5	0.2	BS170	0.195	0.4	3-62
	5	0.5	VN0610LL	0.12	0.4	3-823
	7.5	0.5	VN2222LL	0.099	0.4	3-825
30	1.2	1	VN0300L	0.4	0.4	**

**Contact Motorola sales office for data sheet.
†Depletion Mode



TO-236AA
(SOT-23)
CASE 318-02

Table 22 — Surface Mount — Case 318-02

V(BR)DSS (Volts) Min	r _{DS(on)} @ I _D		Device	I _D (Cont) (Amp) Max	P _D @ T _C = 25°C Watts Max	Package	Page
	Max	(Ohms) (Amp)					
100	6	0.1	BSS123	0.17	0.2	318-02	3-65
60	5	0.2	MMBF170	0.5	0.2	318-02	3-188
	7.5	0.5	2N7002	0.8	0.2	318-02	3-60

TO-220 Leadforms

<p>LEADFORM AJ</p>	<p>LEADFORM AK</p>	<p>LEADFORM S</p>
<p>LEADFORM W</p>	<p>LEADFORM WC</p>	<p>LEADFORM 2A</p>
<p>LEADFORM 3</p>	<p>LEADFORM 3A</p>	<p>LEADFORM 5F</p>
<p>LEADFORM 5FA</p>	<p>LEADFORM 5R</p>	<p>LEADFORM 5RA</p>
<p>LEADFORM 10R</p>	<p>LEADFORM 10RC</p>	<p>LEADFORM 15FA</p>
<p>LEADFORM 18</p>	<p>LEADFORM 16A</p>	<p>Ordering Information: To purchase a leadformed device, contact your local sales office and advise which leadform is required. The sales office will contact the factory and obtain a part number to be used to order the leadformed device.</p>